



RQ3E100GNTB Information



For Reference Only

Part Number RQ3E100GNTB

Manufacturer Rohm Semiconductor

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 30V 10A 8-HSMT

Package 8-PowerVDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RQ3E100GNTB Specifications

Manufacturer Part Number	RQ3E100GNTB
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerVDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	7.9nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	420pF @ 15V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	2W (Ta), 15W (Tc)
Rds On (Max) @ Id, Vgs	11.7 mOhm @ 10A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-HSMT (3.2x3)
Package / Case	8-PowerVDFN
	Report errors?

RQ3E100GNTB Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RQ3E100GNTB Payment Methods



















RQ3E100GNTB Shipping Methods













If you have any question about RQ3E100GNTB, please do not hesitate to contact us!

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